VS-UFB130FA40

Vishay Semiconductors

Insulated Ultrafast Rectifier Module, 130 A



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PRIMARY CHARACTERISTICS						
V _R	400 V					
$I_{F(AV)}$ per module at $T_C = 114 \text{ °C}$	130 A					
t _{rr}	40 ns					
Туре	Modules - diode FRED Pt [®]					
Package	SOT-227					

FEATURES

- Two fully independent diodes
- Fully insulated package
- Ultrafast, soft reverse recovery, with high ROHS operation junction temperature (T_J max. = 175 °C)
- Low forward voltage drop
- Optimized for power conversion: welding and industrial SMPS applications
- Easy to use and parallel
- Industry standard outline
- UL approved file E78996
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The VS-UFB130FA40 insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The diodes structure, and its life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Cathode to anode voltage	V _R		400	V		
Continuous forward current per diode	I _F	T _C = 123 °C	65	٨		
Single pulse forward current per diode	I _{FSM}	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	800	A		
Maximum power dissipation per module	PD	T _C = 123 °C	144	W		
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 min	2500	V		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	400	-	-	
Forward voltage	V _{FM}	I _F = 60 A	-	1.16	1.37	V
		I _F = 60 A, T _J = 175 °C	-	0.93	1.09	
Deverse lectrose everent	I _{RM}	$V_{R} = V_{R}$ rated	-	-	50	μA
Reverse leakage current		$T_J = 175 \text{ °C}, V_R = V_R \text{ rated}$	-	-	1	mA
Junction capacitance	CT	V _R = 400 V	-	67	-	pF

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
	I _F = 1		I _F = 1.0 A, dI _F /dt = 200 A/μs, V _R = 30 V		= 200 A/ μ s, V _R = 30 V	-	40	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	86	-	ns		
		T _J = 125 °C	1 50 4	-	155	-			
	T _J = 25 °C	I _F = 50 A dI _F /dt = 200 A/µs	-	8.4	-	А			
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm B} = 200 \text{ V}$	-	18.4	-	A		
Reverse recovery charge	Q _{rr}	T _J = 25 °C	v _R – 200 v	-	350	-	nC		
		T _J = 125 °C		-	1400	-			

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction-to-case, single leg conducting	Р		-	-	0.72	
Junction-to-case, both leg conducting	R _{thJC}		-	-	0.36	°C/W
Case to heatsink	R _{thCS}	Flat, greased surface	-	0.10	-	
Weight			-	30	-	g
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				S	OT-227	

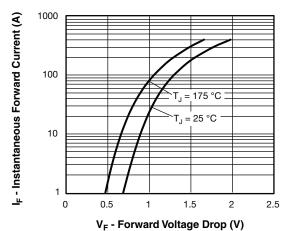


Fig. 1 - Typical Forward Voltage Drop Characteristics (Per Leg)

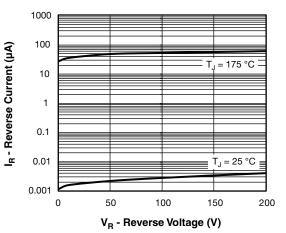


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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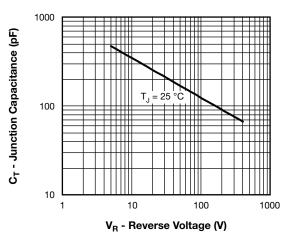


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

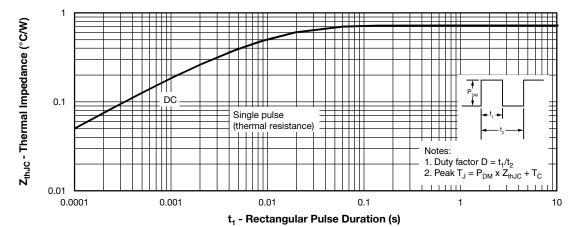
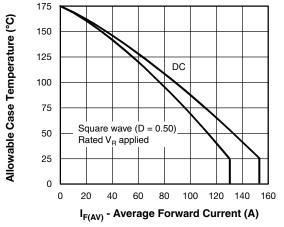
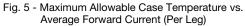
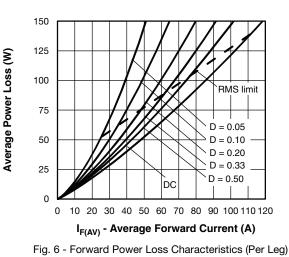


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)









⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = 80 \%$ rated V_R

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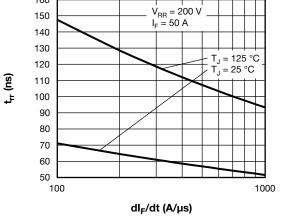


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

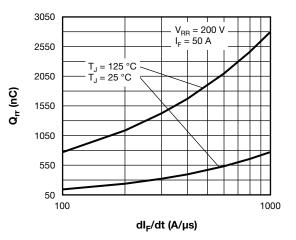


Fig. 8 - Typical Stored Charge vs. dl_F/dt

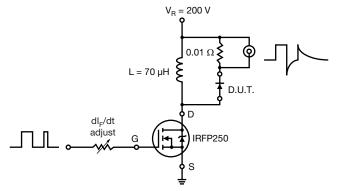
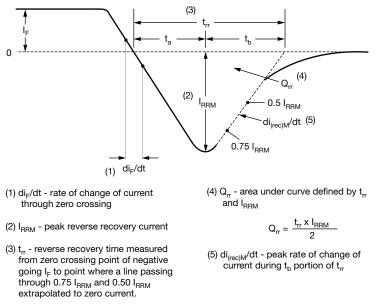
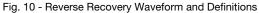


Fig. 9 - Reverse Recovery Parameter Test Circuit

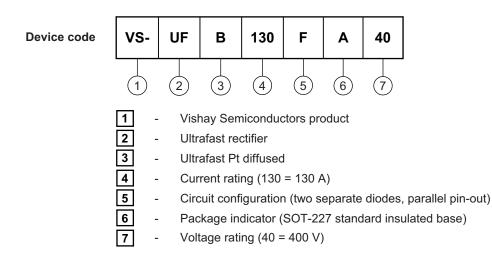








ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING			
		Lead Assignment			
Two separate diodes, parallel pin-out	F				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95423				
Packaging information	www.vishay.com/doc?95425				



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